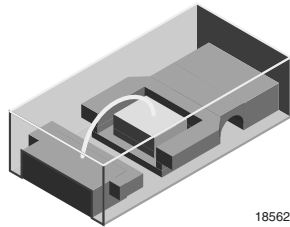




Low Current 0603 SMD LED



DESCRIPTION

The new 0603 LED series have been designed in the smallest SMD package. This innovative 0603 LED technology opens the way to

- smaller products of higher performance
- more design in flexibility
- enhanced applications

The 0603 LED is an obvious solution for small-scale, high power products that are expected to work reliability in an arduous environment.

PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD 0603
- Product series: low current
- Angle of half intensity: $\pm 80^\circ$

FEATURES

- Smallest SMD package 0603 with exceptional brightness
1.6 mm x 0.8 mm x 0.6 mm (L x W x H)
- High reliability lead frame based
- Temperature range - 40 °C to + 100 °C
- Footprint compatible to 0603 chipled
- Wavelength 633 nm (red), 606 nm (orange), 587 nm (yellow)
- AllnGaP technology
- Compatible to IR reflow soldering
- Viewing angle: extremely wide 160°
- Grouping parameter: luminous intensity, wavelength
- Available in 8 mm tape
- Lead (Pb)-free device
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- Preconditioning: acc. to JEDEC level 2
- Automotive qualified AEC-Q101



APPLICATIONS

- Backlight keypads
- Navigation systems
- Cellular phone displays
- Displays for industrial control systems
- Automotive features
- Miniaturized color effects
- Traffic displays

PARTS TABLE	
PART	COLOR, LUMINOUS INTENSITY
TLMS1000-GS08	Red, $I_V = 4$ mcd (typ.)
TLMS1001-GS08	Red, $I_V = (4.5$ to $9)$ mcd (typ.)
TLMO1000-GS08	Soft orange, $I_V = 7.5$ mcd (typ.)
TLMY1000-GS08	Yellow, $I_V = 7.5$ mcd (typ.)



ABSOLUTE MAXIMUM RATINGS ¹⁾ TLMS100., TLMO1000, TLMY1000				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage ²⁾		V_R	12	V
DC Forward current	$T_{amb} \leq 95\text{ }^\circ\text{C}$	I_F	15	mA
Surge forward current	$t_p \leq 10\text{ }\mu\text{s}$	I_{FSM}	0.1	A
Power dissipation		P_V	40	mW
Junction temperature		T_j	120	$^\circ\text{C}$
Operating temperature range		T_{amb}	- 40 to + 100	$^\circ\text{C}$
Storage temperature range		T_{stg}	- 40 to + 100	$^\circ\text{C}$
Soldering temperature	acc. Vishay spec	T_{sd}	260	$^\circ\text{C}$
Thermal resistance junction/ambient	mounted on PC board (pad size > 5 mm ²)	R_{thJA}	500	K/W

Note:

¹⁾ $T_{amb} = 25\text{ }^\circ\text{C}$, unless otherwise specified

²⁾ Driving the LED in reverse direction is suitable for short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ TLMS100., RED							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	$I_F = 2\text{ mA}$	TLMS1000	I_V	1.8	4		mcd
		TLMS1001	I_V	4.5		9	mcd
Dominant wavelength	$I_F = 2\text{ mA}$		λ_d	624	628	636	nm
Peak wavelength	$I_F = 2\text{ mA}$		λ_p		640		nm
Angle of half intensity	$I_F = 2\text{ mA}$		φ		± 80		deg
Forward voltage	$I_F = 2\text{ mA}$		V_F		1.8	2.6	V
Reverse voltage	$I_R = 10\text{ }\mu\text{A}$		V_R	6			V
Junction capacitance	$V_R = 0, f = 1\text{ MHz}$		C_j		15		pF

Note:

¹⁾ $T_{amb} = 25\text{ }^\circ\text{C}$, unless otherwise specified

OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ TLMO1000, SOFT ORANGE							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Luminous intensity	$I_F = 2\text{ mA}$	I_V	3.55	7.5		mcd	
Dominant wavelength	$I_F = 2\text{ mA}$	λ_d	600	605	609	nm	
Peak wavelength	$I_F = 2\text{ mA}$	λ_p		610		nm	
Angle of half intensity	$I_F = 2\text{ mA}$	φ		± 80		deg	
Forward voltage	$I_F = 2\text{ mA}$	V_F		1.8	2.6	V	
Reverse voltage	$I_R = 10\text{ }\mu\text{A}$	V_R	6			V	
Junction capacitance	$V_R = 0, f = 1\text{ MHz}$	C_j		15		pF	

Note:

¹⁾ $T_{amb} = 25\text{ }^\circ\text{C}$, unless otherwise specified



OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ TLMY1000, YELLOW						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	$I_F = 2 \text{ mA}$	I_V	3.55	7.5		mcd
Dominant wavelength	$I_F = 2 \text{ mA}$	λ_d	580	588	595	nm
Peak wavelength	$I_F = 2 \text{ mA}$	λ_p		591		nm
Angle of half intensity	$I_F = 2 \text{ mA}$	φ		± 80		deg
Forward voltage	$I_F = 2 \text{ mA}$	V_F		1.8	2.6	V
Reverse voltage	$I_R = 10 \mu\text{A}$	V_R	6			V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	C_j		15		pF

Note:

¹⁾ $T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified

COLOR CLASSIFICATION				
GROUP	DOMINANT WAVELENGTH (nm)			
	YELLOW		ORANGE	
	MIN.	MAX.	MIN.	MAX.
2	580	583	600	603
3	583	586	602	605
4	586	589	604	607
5	589	592	606	609
6	592	595		

Note:

Wavelengths are tested at a current pulse duration of 25 ms and an accuracy of $\pm 1 \text{ nm}$

LUMINOUS INTENSITY CLASSIFICATION		
GROUP	LUMINOUS INTENSITY (mcd)	
	MIN.	MAX.
G1	1.80	2.24
G2	2.24	2.80
H1	2.80	3.55
H2	3.55	4.50
J1	4.50	5.60
J2	5.60	7.10
K1	7.10	9.00
K2	9.00	11.20
L1	11.20	14.00
L2	14.00	18.00

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of $\pm 11 \%$.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped in any one reel.

In order to ensure availability, single wavelength groups will not be orderable.

Vishay Semiconductors

TYPICAL CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

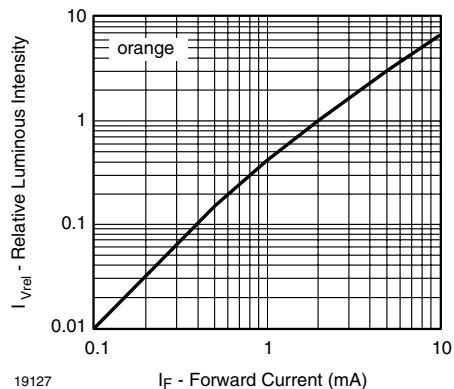


Figure 1. Relative Luminous Intensity vs. Forward Current

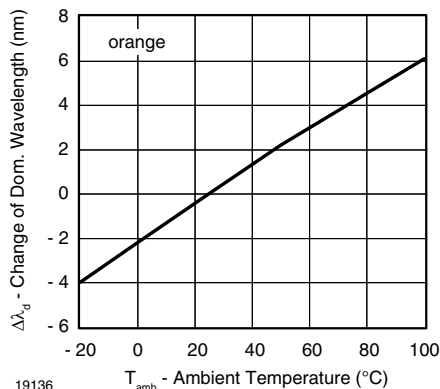


Figure 4. Change of Dominant Wavelength vs. Ambient Temperature

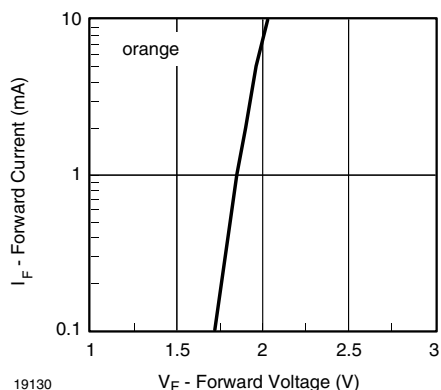


Figure 2. Forward Current vs. Forward Voltage

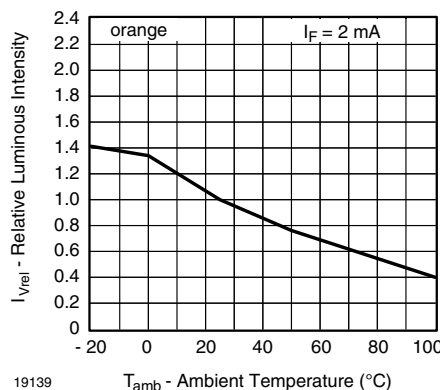


Figure 5. Relative Luminous Intensity vs. Ambient Temperature

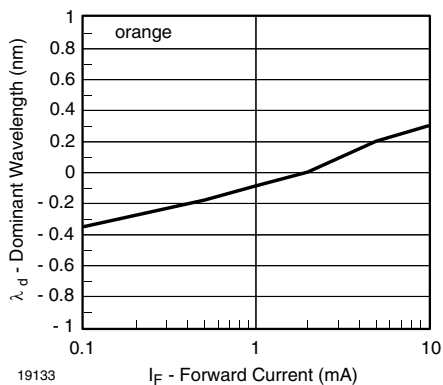


Figure 3. Dominant Wavelength vs. Forward Current

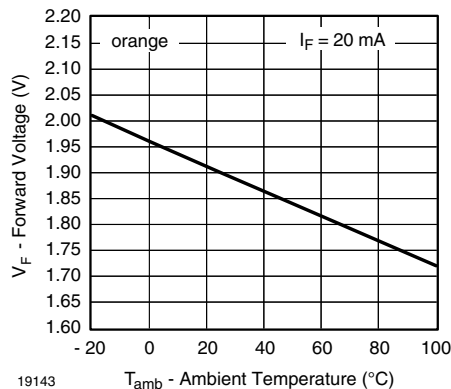


Figure 6. Forward Voltage vs. Ambient Temperature

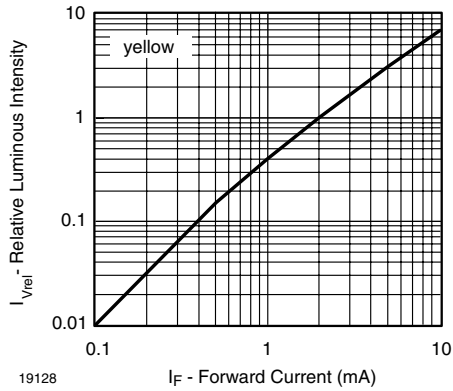


Figure 7. Relative Luminous Intensity vs. Forward Current

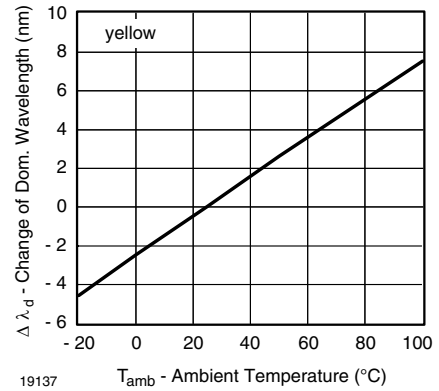


Figure 10. Change of Dominant Wavelength vs. Ambient Temperature

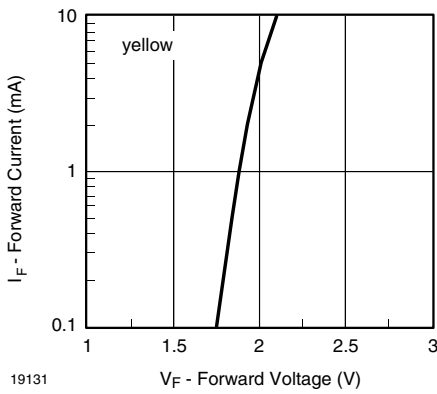


Figure 8. Forward Current vs. Forward Voltage

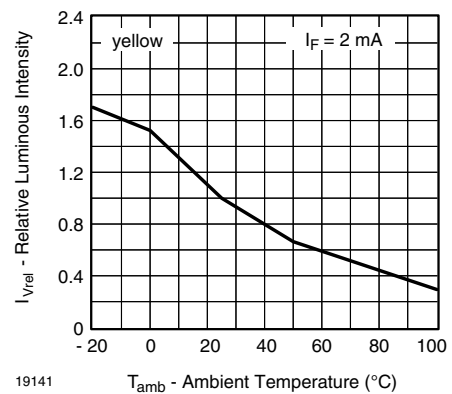


Figure 11. Relative Luminous Intensity vs. Amb. Temperature

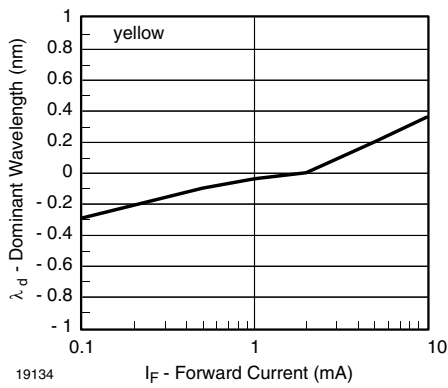


Figure 9. Dominant Wavelength vs. Forward Current

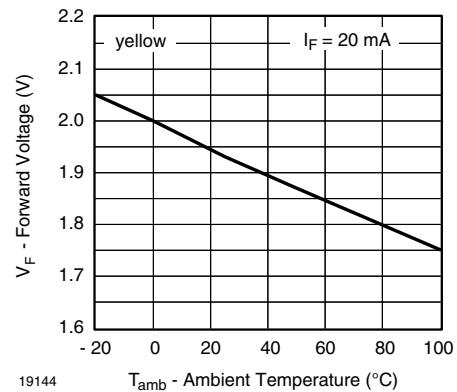


Figure 12. Forward Voltage vs. Ambient Temperature

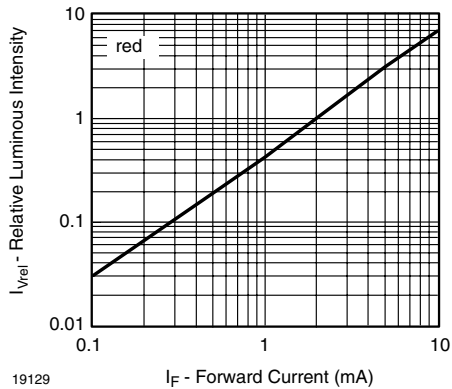


Figure 13. Relative Luminous Intensity vs. Forward Current

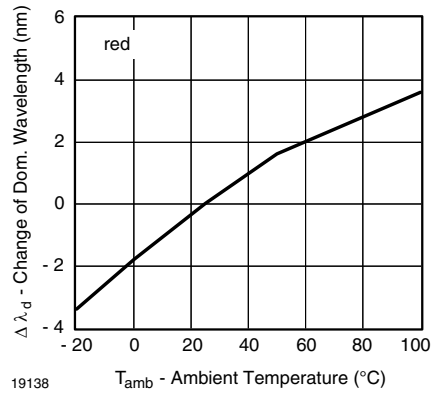


Figure 16. Change of Dominant Wavelength vs. Ambient Temperature

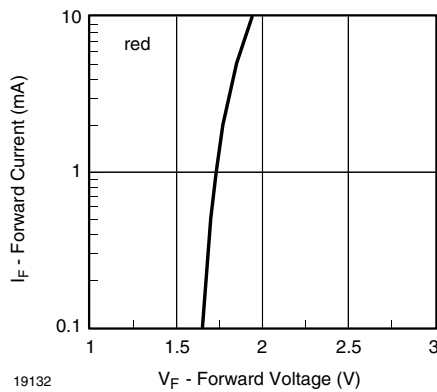


Figure 14. Forward Current vs. Forward Voltage

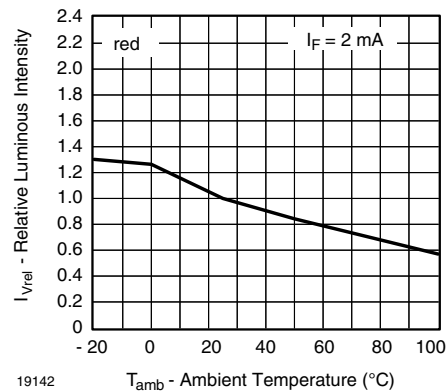


Figure 17. Relative Luminous Intensity vs. Amb. Temperature

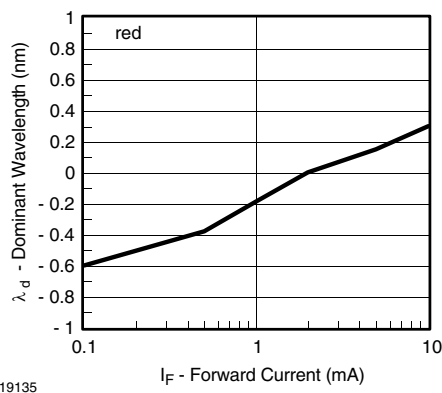


Figure 15. Dominant Wavelength vs. Forward Current

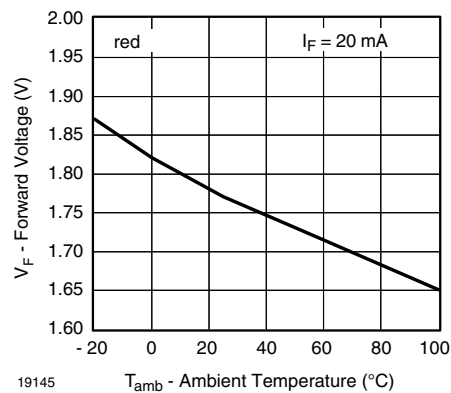


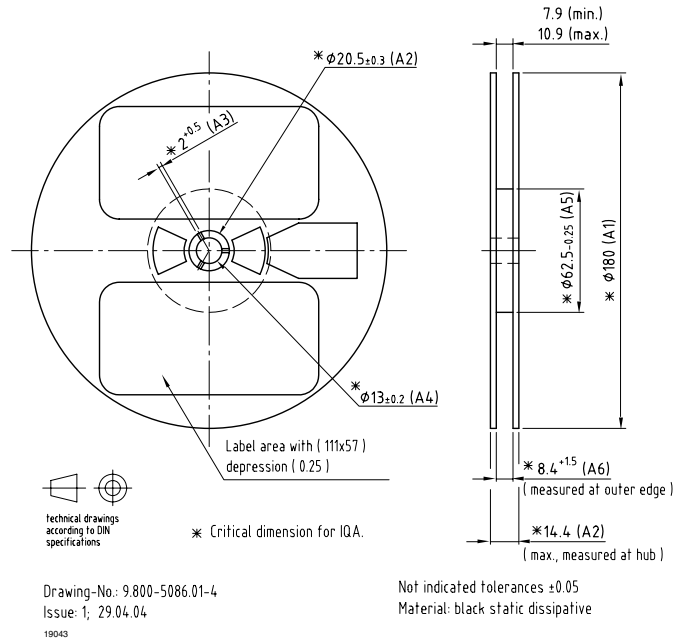
Figure 18. Forward Voltage vs. Ambient Temperature



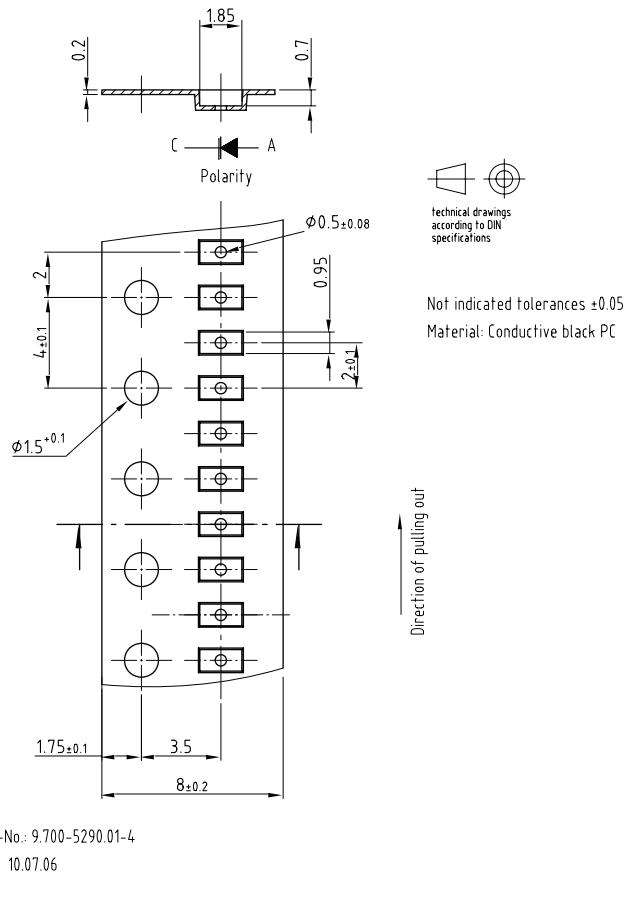
TLMO1000, TLMS1000, TLMS1001, TLMY1000

Vishay Semiconductors

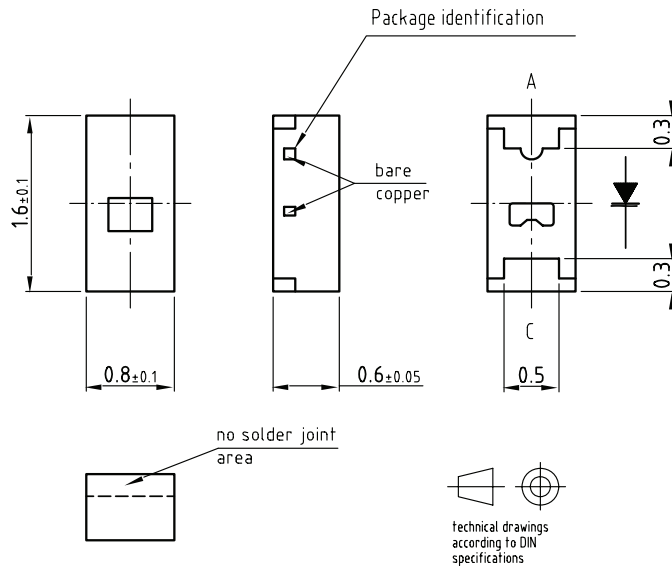
REEL DIMENSIONS in millimeters



TAPE DIMENSIONS in millimeters

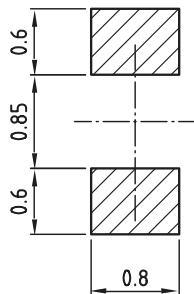


PACKAGE DIMENSIONS in millimeters



Not indicated tolerances ± 0.1

Recommended solder pad



Drawing-No.: 6.541-5056.01-4

Issue: 2; 04.05.05

19426

SOLDERING PROFILE

IR Reflow Soldering Profile for lead (Pb)-free soldering
Preconditioning acc. to JEDEC Level 2

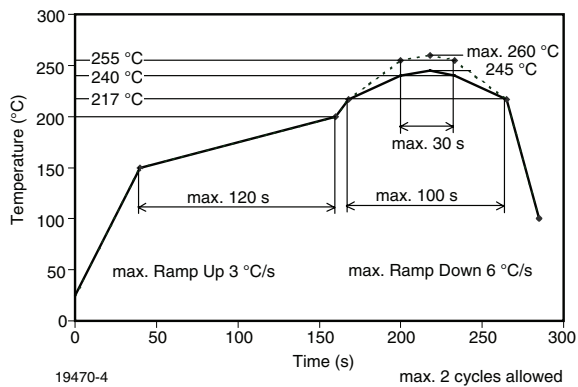
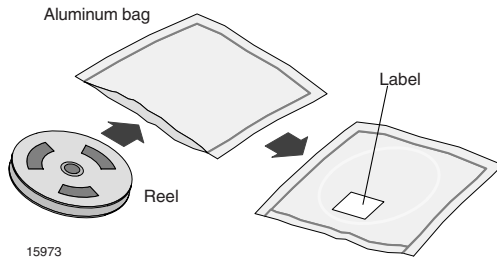


Figure 19. Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020C)

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminium bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 1 year under these conditions moisture content will be too high for reflow soldering.

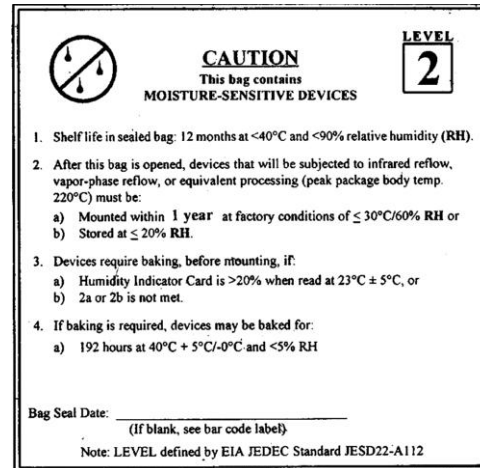
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C/- 0 °C and < 5 % RH (dry air/nitrogen) or

96 h at 60 °C + 5 °C and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2 label is included on all dry bags.



Example of JESD22-A112 level 2 label

17028

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.



Vishay Semiconductors

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.